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EMIF09-SD01F3

9-line IPAD[™], EMI filter and ESD protection

Features

- 9-line EMI low-pass filter and ESD protection
- High efficiency in EMI filtering
- Lead-free package
- 400 µm pitch
- Very low PCB space occupation: < 4 mm²
- Very thin package: 0.6 mm
- High reliability offered by monolithic integration
- Reduction of parasitic elements thanks to CSP integration

Complies with the following standards

- IEC61000-4-2 level 4 on external pins:
 - 15 kV (air discharge)
 - 8 kV (contact discharge)
- IEC61000-4-2 level 2 on internal pins:
 - 2 kV (air discharge)
 - 2 kV (contact discharge)
- MIL STD 883F Method 3015.7 Class 3

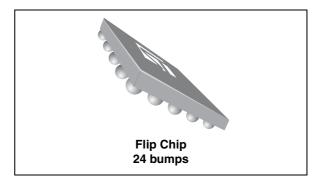
Application

 Secure digital memory card in mobile phones and communication systems

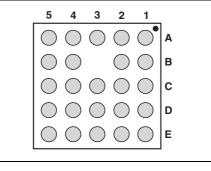
Description

The EMIF09-SD01F3 is a highly integrated array designed to suppress EMI/RFI noise for secure digital memory cards. The EMIF09-SD01F3 is in a Flip Chip package to offer space saving and high RF performance.

This low-pass filter includes ESD protection circuitry, which prevents damage to the protected device when subjected to ESD surges up 15 kV. This filter also has a low line capacitance to be compatible with high data rate signals.







TM: IPAD is a trademark of STMicroelectronics.

1 Characteristics

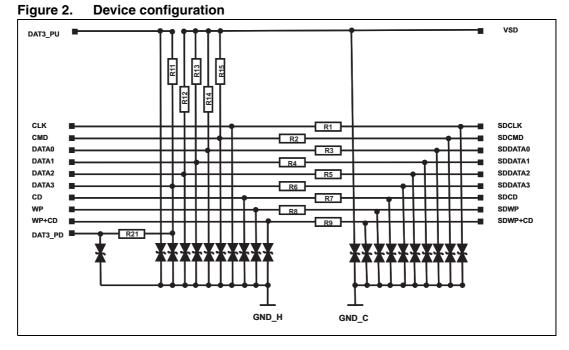


Table 1.Pin-signal attribution

Pin	Description								
A1	DATA2	B1	CD	C1	DAT3_PD	D1	WP+CD	E1	DATA1
A2	DATA3	B2	CMD	C2	WP	D2	CLK	E2	DATA0
A3	GND_H	B3		C3	DAT3_PU	D3	GND_C	E3	GND_C
A4	SDDATA2	B4	SDCD	C4	SDWP	D4	SDWP+CD	E4	SDDATA1
A5	SDDATA3	B5	SDCMD	C5	VSD	D5	SDCLK	E5	SDDATA0

Table 2. Absolute ratings (limiting values)

Symbol	Parameter	Value	Unit
	Internal pins (A1, B1, C1, D1, E1, A2, B2, C2, D2, E2, C3)		
	ESD discharge IEC 61000-4-2, air discharge	2	
Ň	ESD discharge IEC 61000-4-2, contact discharge	2	
V _{PP}	External pins (A4, B4, C4, D4, E4, A5, B5, C5, D5, E5)		kV
	ESD discharge IEC 61000-4-2, air discharge	15	
	ESD discharge IEC 61000-4-2, contact discharge	8	
Тj	Junction temperature	125	°C
T _{op}	Operating temperature range	-30 to + 85	°C
T _{stg}	Storage temperature range	-55 to 150	°C

GND bumps (GND_H and GND_C - A3, D3 and E3) must be connected to ground on the printed circuit board for ESD testing and RF measurements.



Table 3.	Electrical characteristics (T _{amb}	= 25 °C)					
Symbol	Parameters						
V _{BR}	Breakdown voltage		' <u>↑</u>				
I _{RM}	Leakage current @ V _{RM}			I _{PP}			
V _{RM}	Stand-off voltage						
V _{CL}	Clamping voltage						
R _d	Dynamic impedance						
I _{PP}	Peak pulse current			I _R			
R _{I/O}	Series resistance between input and output			I _{PP}			
C _{line}	Input capacitance per line		1	Ι			
Symbol	Test conditions		Min	Тур	Max	Unit	
V _{BR}	I _R = 1 mA		6		20	V	
I _{RM}	V _{RM} = 5 V per line			50	200	nA	
R1, R2, R3, R4, R5, R6, R7, R8, R9	Tolerance ± 20%			40		Ω	
R11, R12, R13, R14	Tolerance ± 30%			50		kΩ	
R15	Tolerance ± 30%			15		kΩ	
R21	Tolerance ± 30%			470		kΩ	
C _{line}	$V_{\text{line}} = 0 \text{ V}, V_{\text{OSC}} = 30 \text{ mV}, \text{ F} = 1 \text{ MH}$ (under zero light conditions)			20	pF		

Table 3. Electrical characteristics ($T_{amb} = 25 \degree C$)



Figure 3. S21(dB) all lines attenuation measurement

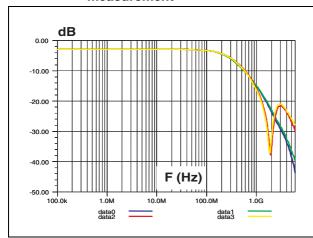
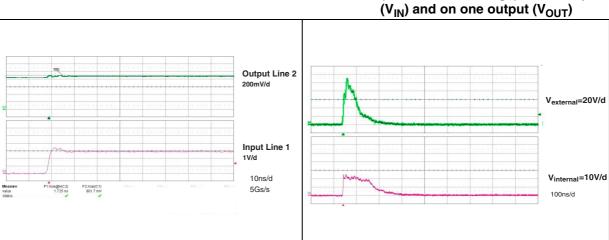
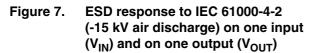
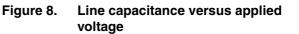


Figure 5. Digital crosstalk measurement

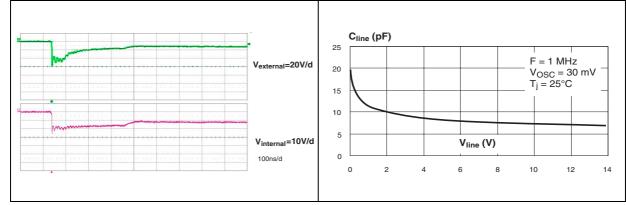
Figure 6. ESD response to IEC 61000-4-2 (+15 kV air discharge) on one input





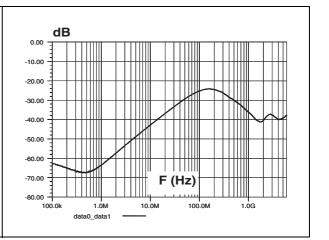


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EMIF09-SD01F3

Figure 4. Analog cross talk measurement



2 Application information

Figure 9. Aplac model

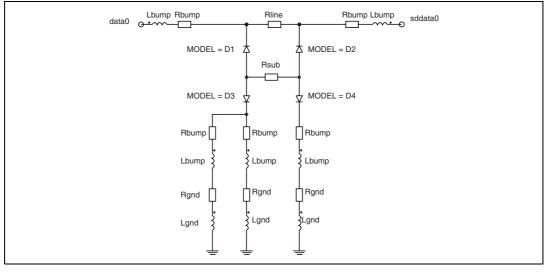
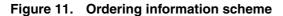


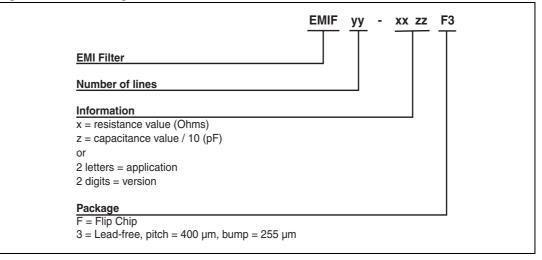
Figure 10. Aplac model variables

<u>Variables</u> aplacvar Rline 40 aplacvar C d1 14.5p	<u>Diode D1</u> BV=7 IBV=1m	<u>Diode D2</u> BV=7 IBV=1m	<u>Diode D3</u> BV=7 IBV=1m	<u>Diode D4</u> BV=7 IBV=1m	
aplacvar C_d2 6.5p	CJO=C_d1	CJO=C_d2	CJO=C_d3	CJO=C_d4	
aplacvar C_d3 303p	M=0.28	M=0.28	M=0.28	M=0.28	
aplacvar C_d4 14.5p	RS=1.13	RS=0.8	RS=0.37	RS=1.13	
aplacvar Lbump 43pH	VJ=0.6	VJ=0.6	VJ=0.6	VJ=0.6	
aplacvar Rbump 17m	TT=100n	TT=100n	TT=100n	TT=100n	
aplacvar Cbump 150f					
aplacvar Lgnd 150pH					
aplacvar Rgnd 10m					
aplacvar Rsub 5					



3 Ordering information scheme

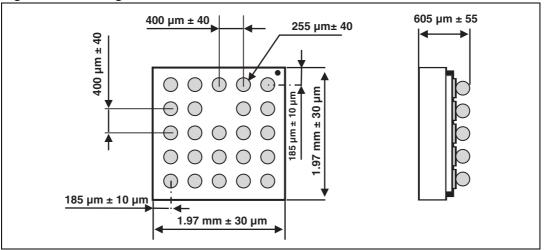


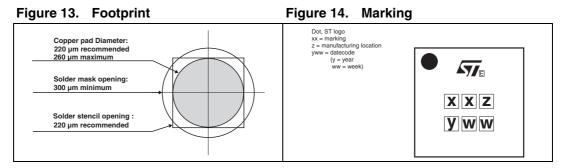


4 Package information

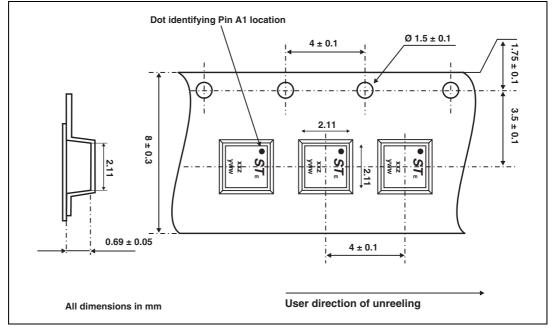
In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at *www.st.com*.

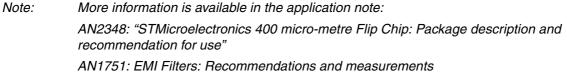
Figure 12. Package dimensions











5 Ordering information

Table 4. Orde	ering inf	ormation
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Order code	Marking	Package	Weight	Base qty	Delivery mode
EMIF09-SD01F3	GZ	Flip Chip	5.2 mg	5000	Tape and reel (7")



6 Revision history

Table 5.Document revision history

Date	Revision	Changes	
19-Oct-2005	1	Initial release.	
09-Feb-2006	2	Tape cavity dimensions added in Figure 13. Other graphics improved.	
22-Mar-2006	3	Reformatted to current standard. Typical and maximum values updated for ${\rm I}_{\rm RM}$ in Electrical characteristics, page 3.	
28-Apr-2008	4	Updated ECOPACK statement. Updated <i>Figure 11</i> , <i>Figure 12</i> and <i>Figure 15</i> . Reformatted to current standards.	



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